

TC74HC151AP, TC74HC151AF, TC74HC151AFN

8 - CHANNEL MULTIPLEXER

The TC74HC151A is a high speed CMOS 8 - CHANNEL MULTIPLEXER fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

One of eight data input signals (D0 - D7) is selected by decoding of the three - bit address input (A, B, C). The selected data appears on two outputs : non - inverting (Y) and inverting (W).

The strobe input provides two output conditions ; a low level on the strobe input transfers the selected data to the outputs. A high level on the strobe input sets the Y output low and the W output high without regard to the data or select input conditions.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES :

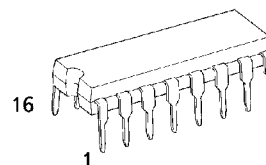
- High Speed..... $t_{pd} = 15ns(\text{typ.})$ at $V_{CC} = 5V$
- Low Power Dissipation..... $I_{CC} = 4\mu A(\text{Max.})$ at $T_a = 25^\circ C$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC} (\text{Min.})$
- Output Drive Capability..... 10 LSTTL Loads
- Symmetrical Output Impedance... $| I_{OH} | = I_{OL} = 4mA(\text{Min.})$
- Balanced Propagation Delays..... $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range... $V_{CC} (\text{opr.}) = 2V \sim 6V$
- Pin and Function Compatible with 74LS151

TRUTH TABLE

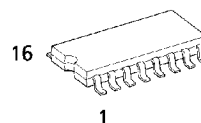
INPUTS				OUTPUTS	
SELECT			STROBE	Y	W
C	B	A	\overline{ST}		
X	X	X	H	L	H
L	L	L	L	D0	$\overline{D0}$
L	L	H	L	D1	$\overline{D1}$
L	H	L	L	D2	$\overline{D2}$
L	H	H	L	D3	$\overline{D3}$
H	L	L	L	D4	$\overline{D4}$
H	L	H	L	D5	$\overline{D5}$
H	H	L	L	D6	$\overline{D6}$
H	H	H	L	D7	$\overline{D7}$

X : Don't Care

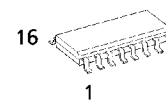
(Note) The JEDEC SOP (FN) is not available in Japan.



P (DIP16-P-300-2.54A)
Weight : 1.00g (Typ.)

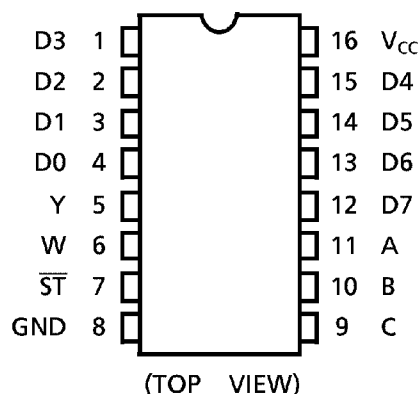


F (SOP16-P-300-1.27)
Weight : 0.18g (Typ.)

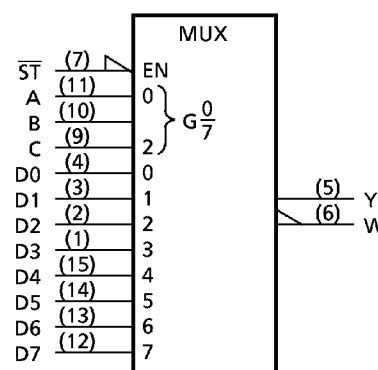


FN (SOL16-P-150-1.27)
Weight : 0.13g (Typ.)

PIN ASSIGNMENT



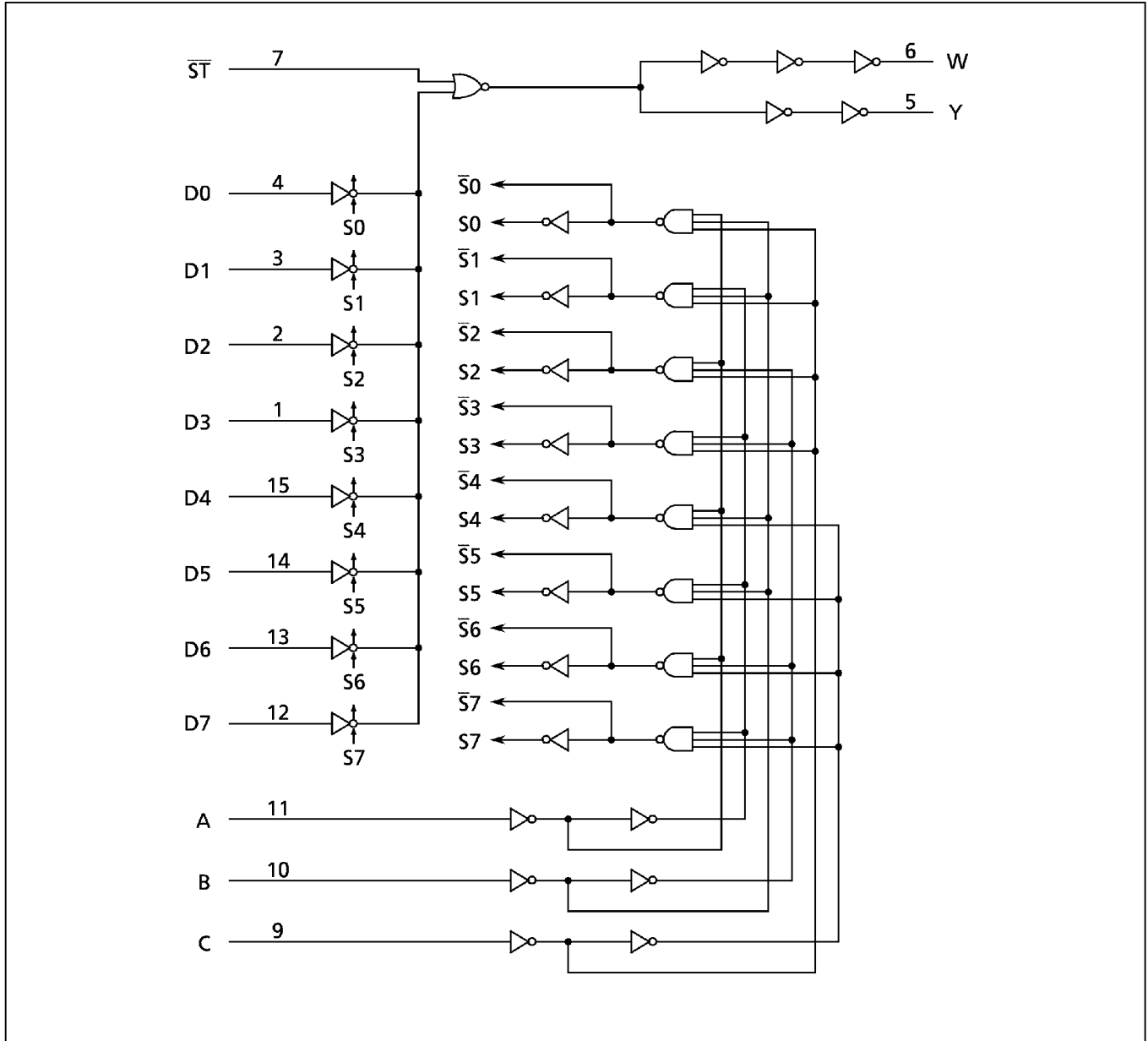
IEC LOGIC SYMBOL



980508EBA2

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SYSTEM DIAGRAM



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ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	-0.5~7	V
DC Input Voltage	V_{IN}	-0.5~ $V_{CC}+0.5$	V
DC Output Voltage	V_{OUT}	-0.5~ $V_{CC}+0.5$	V
Input Diode Current	I_{IK}	±20	mA
Output Diode Current	I_{OK}	±20	mA
DC Output Current	I_{OUT}	±25	mA
DC V_{CC} / Ground Current	I_{CC}	±50	mA
Power Dissipation	P_D	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T_{stg}	-65~150	°C

*500mW in the range of $T_a = -40^{\circ}\text{C} \sim 65^{\circ}\text{C}$. From $T_a = 65^{\circ}\text{C}$ to 85°C a derating factor of $-10\text{mW}/^{\circ}\text{C}$ shall be applied until 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	2~6	V
Input Voltage	V_{IN}	0~ V_{CC}	V
Output Voltage	V_{OUT}	0~ V_{CC}	V
Operating Temperature	T_{opr}	-40~85	°C
Input Rise and Fall Time	t_r, t_f	0~1000 ($V_{CC} = 2.0\text{V}$) 0~500 ($V_{CC} = 4.5\text{V}$) 0~400 ($V_{CC} = 6.0\text{V}$)	ns

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	$T_a = 25^{\circ}\text{C}$			$T_a = -40 \sim 85^{\circ}\text{C}$		UNIT				
				MIN.	TYP.	MAX.	MIN.	MAX.					
High - Level Input Voltage	V_{IH}		2.0	1.50	—	—	1.50	—	V				
			4.5	3.15	—	—	3.15	—					
			6.0	4.20	—	—	4.20	—					
Low - Level Input Voltage	V_{IL}		2.0	—	—	0.50	—	0.50	V				
			4.5	—	—	1.35	—	1.35					
			6.0	—	—	1.80	—	1.80					
High - Level Output Voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -20\mu\text{A}$	2.0	1.9	2.0	—	1.9	—	V			
				4.5	4.4	4.5	—	4.4	—				
				6.0	5.9	6.0	—	5.9	—				
Low - Level Output Voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 20\mu\text{A}$	2.0	—	0.0	0.1	—	0.1	V			
				4.5	—	0.0	0.1	—	0.1				
				6.0	—	0.0	0.1	—	0.1				
Input Leakage Current	I_{IN}	$V_{IN} = V_{CC}$ or GND	6.0	—	—	±0.1	—	±1.0	μA				
				Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC}$ or GND	6.0	—		—	4.0	—	40.0

AC ELECTRICAL CHARACTERISTICS ($C_L = 15\text{pF}$, $V_{CC} = 5\text{V}$, $T_a = 25^\circ\text{C}$, Input $t_r = t_f = 6\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	t_{TLH} t_{THL}		—	4	8	ns
Propagation Delay Time (D–Y)	t_{PLH} t_{PHL}		—	15	24	
Propagation Delay Time (D–W)	t_{PLH} t_{PHL}		—	15	24	
Propagation Delay Time (\overline{ST} –Y)	t_{PLH} t_{PHL}		—	10	17	
Propagation Delay Time (\overline{ST} –W)	t_{PLH} t_{PHL}		—	10	17	
Propagation Delay Time (A, B, C–Y)	t_{PLH} t_{PHL}		—	19	31	
Propagation Delay Time (A, B, C–W)	t_{PLH} t_{PHL}		—	19	31	

AC ELECTRICAL CHARACTERISTICS ($C_L = 50\text{pF}$, Input $t_r = t_f = 6\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION	$T_a = 25^\circ\text{C}$			$T_a = -40\sim 85^\circ\text{C}$		UNIT	
			V_{CC} (V)	MIN.	TYP.	MAX.	MIN.		MAX.
Output Transition Time	t_{TLH} t_{THL}		2.0	—	30	75	—	95	ns
			4.5	—	8	15	—	19	
			6.0	—	7	13	—	16	
Propagation Delay Time (D–Y)	t_{PLH} t_{PHL}		2.0	—	65	140	—	175	
			4.5	—	18	28	—	35	
			6.0	—	15	24	—	30	
Propagation Delay Time (D–W)	t_{PLH} t_{PHL}		2.0	—	65	140	—	175	
			4.5	—	18	28	—	35	
			6.0	—	15	24	—	30	
Propagation Delay Time (\overline{ST} –Y)	t_{PLH} t_{PHL}		2.0	—	36	100	—	125	
			4.5	—	12	20	—	25	
			6.0	—	10	17	—	21	
Propagation Delay Time (\overline{ST} –W)	t_{PLH} t_{PHL}		2.0	—	36	100	—	125	
			4.5	—	12	20	—	25	
			6.0	—	10	17	—	21	
Propagation Delay Time (A, B, C–Y)	t_{PLH} t_{PHL}		2.0	—	80	180	—	225	
			4.5	—	23	36	—	45	
			6.0	—	19	31	—	38	
Propagation Delay Time (A, B, C–W)	t_{PLH} t_{PHL}		2.0	—	80	180	—	225	
			4.5	—	23	36	—	45	
			6.0	—	19	31	—	38	
Input Capacitance	C_{IN}		—	5	10	—	10	pF	
Power Dissipation Capacitance	C_{PD} (1)		—	69	—	—	—		

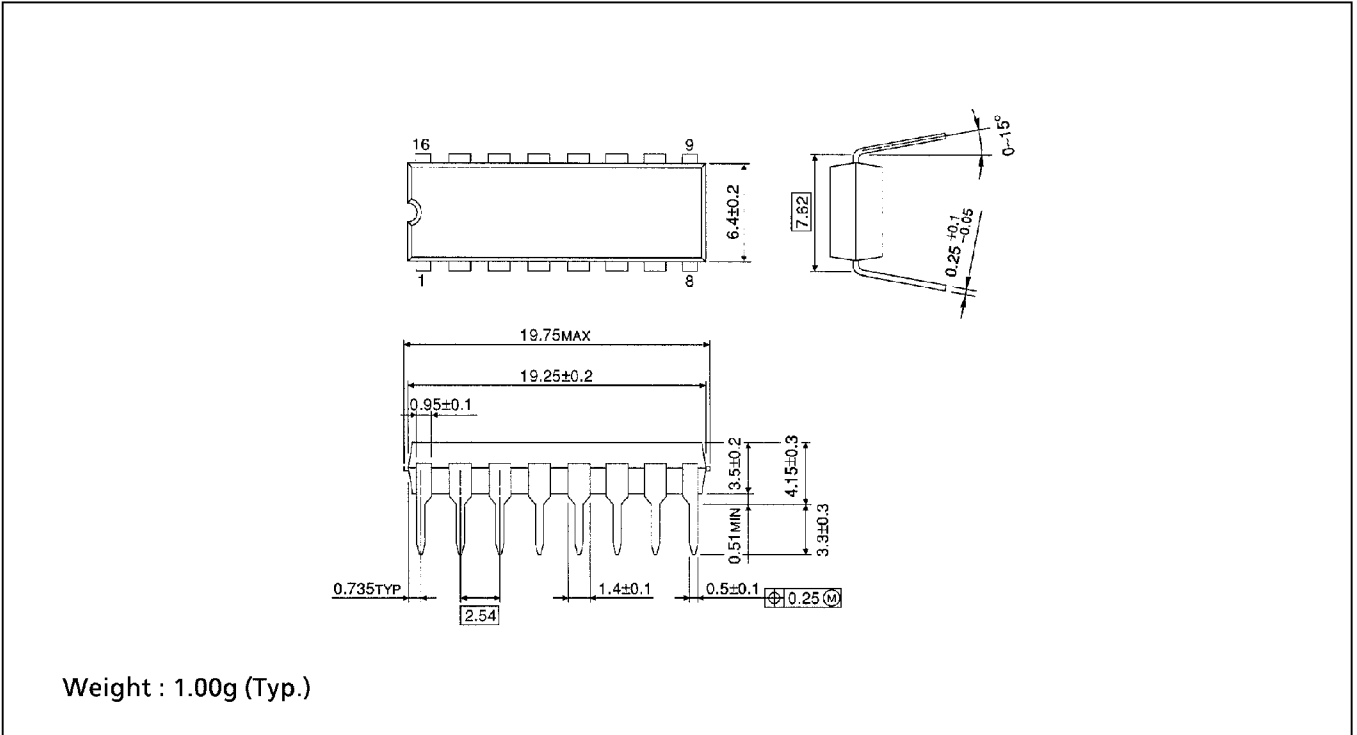
Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

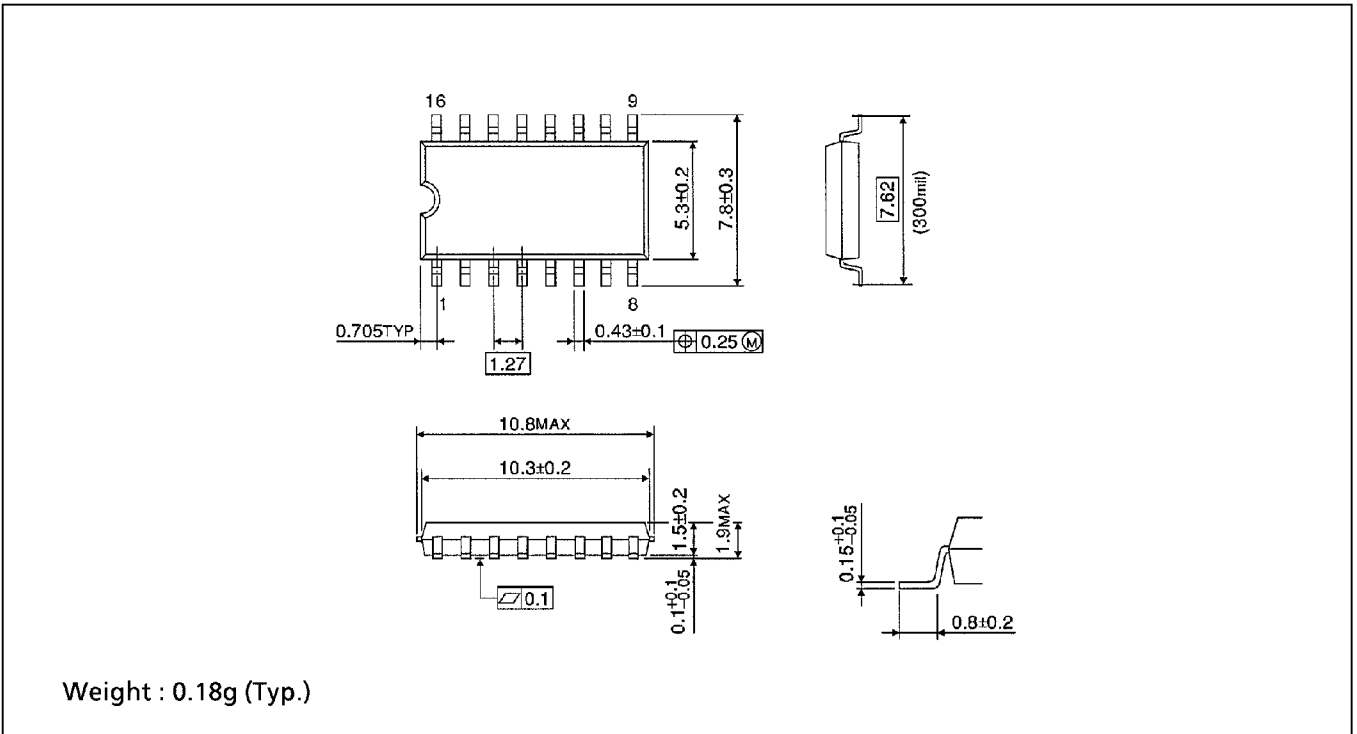
DIP 16PIN OUTLINE DRAWING (DIP16-P-300-2.54A)

Unit in mm



SOP 16PIN (200mil BODY) OUTLINE DRAWING (SOP16-P-300-1.27)

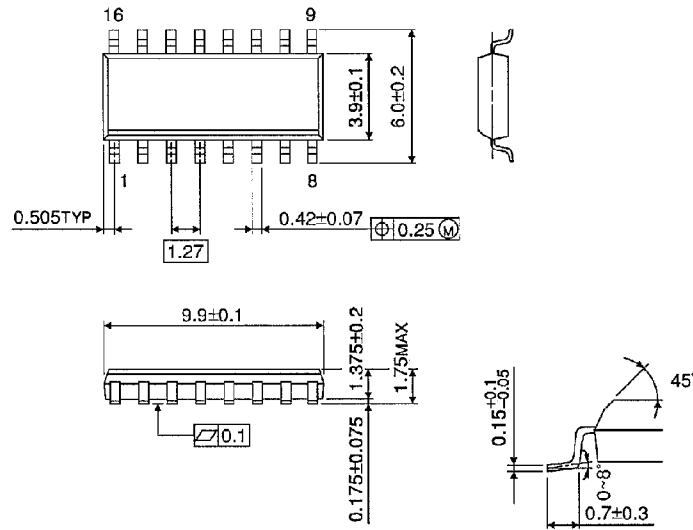
Unit in mm



SOP 16PIN (150mil BODY) OUTLINE DRAWING (SOL16-P-150-1.27)

Unit in mm

(Note) This package is not available in Japan.



Weight : 0.13g (Typ.)